

View Online at <https://aerobasegroup.com/nsn/5961-01-351-1946>

Inclosure Material:

Plastic

Overall Length:

Between 0.660 inches and 0.785 inches

Overall Height:

0.200 inches

Overall Width:

0.325 inches

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-116

Component Name And Quantity:

4 transistor

Mounting Method:

Terminal

Semiconductor Material:

Silicon all semiconductor

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-emitter, base open all semiconductor and 40.0 working peak off-state voltage all semiconductor

Current Rating Per Characteristic:

0.50 milliamperes source cutoff current of standard range all semiconductor

Power Rating Per Characteristic:

1900.0 milliwatts small-signal input power, common-emitter absolute all semiconductor

Maximum Operating Temperature Per Measurement Point:

-65.0 degrees celsius case and 175.0 degrees celsius case

Special Features:

All transistor junction pattern arrangement: pnp

Terminal Type And Quantity:

14 pin

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fig:

A110a0